



# NJG1127HB6

## ■ ABSOLUTE MAXIMUM RATINGS

( $T_a=+25^{\circ}\text{C}$ ,  $Z_s=Z_l=50\Omega$ )

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	$V_{DD}$		5.0	V
Inverter supply voltage	$V_{INV}$		5.0	V
Control voltage	$V_{CTL}$		5.0	V
Input power	$P_{in}$	$V_{DD}=3.3\text{V}$	+22	dBm
Power dissipation	$P_D$	on PCB board, $T_{jmax}=150^{\circ}\text{C}$	160	mW
Operating temperature	$T_{opr}$		-40~+105	$^{\circ}\text{C}$
Storage temperature	$T_{stg}$		-55~+150	$^{\circ}\text{C}$

## ■ ELECTRICAL CHARACTERISTICS 1 (DC CHARACTERISTICS)

(General Conditions:  $T_a=+25^{\circ}\text{C}$ ,  $Z_s=Z_l=50\Omega$ )

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating voltage	$V_{DD}$		2.65	-	4.0	V
Inverter supply voltage	$V_{INV}$		2.65	-	4.0	V
Control voltage (High)_1	$V_{CTL(H)_1}$	$V_{DD}=2.8\text{V}$	1.80	1.85	$V_{DD}+0.3$	V
Control voltage (High)_2	$V_{CTL(H)_2}$	$V_{DD}=3.3\text{V}$	1.80	3.3	$V_{DD}+0.3$	V
Control voltage (Low)	$V_{CTL(L)}$		0	0	0.3	V
Operating current 1(1) (LNA High Gain Mode)	$I_{DD1(1)}$	RF OFF $V_{DD}=V_{INV}=2.8\text{V}$ , $V_{CTL}=1.85\text{V}$	-	10.0	16.0	mA
Operating current 1(2) (LNA Low Gain Mode)	$I_{DD1(2)}$	RF OFF $V_{DD}=V_{INV}=2.8\text{V}$ , $V_{CTL}=0\text{V}$	-	1	5	$\mu\text{A}$
Operating current 2(1) (LNA High Gain Mode)	$I_{DD\_2(1)}$	RF OFF $V_{DD}=V_{INV}=3.3\text{V}$ , $V_{CTL}=3.3\text{V}$	-	13.0	21.0	mA
Operating current 2(2) (LNA Low Gain Mode)	$I_{DD\_2(2)}$	RF OFF $V_{DD}=V_{INV}=3.3\text{V}$ , $V_{CTL}=0\text{V}$	-	1	6	$\mu\text{A}$
Inverter current 1(1) (LNA High Gain Mode)	$I_{INV\_1(1)}$	RF OFF $V_{DD}=V_{INV}=2.8\text{V}$ , $V_{CTL}=1.85\text{V}$	-	150	240	$\mu\text{A}$
Inverter current 1(2) (LNA Low Gain Mode)	$I_{INV\_1(2)}$	RF OFF $V_{DD}=V_{INV}=2.8\text{V}$ , $V_{CTL}=0\text{V}$	-	15	40	$\mu\text{A}$
Inverter current 2(1) (LNA High Gain Mode)	$I_{INV\_2(1)}$	RF OFF $V_{DD}=V_{INV}=3.3\text{V}$ , $V_{CTL}=3.3\text{V}$	-	170	300	$\mu\text{A}$
Inverter current 2(2) (LNA Low Gain Mode)	$I_{INV\_2(2)}$	RF OFF $V_{DD}=V_{INV}=3.3\text{V}$ , $V_{CTL}=0\text{V}$	-	20	50	$\mu\text{A}$
Control current_1	$I_{CTL\_1}$	RF OFF, $V_{CTL}=1.85\text{V}$	-	5	15	$\mu\text{A}$
Control current_2	$I_{CTL\_2}$	RF OFF, $V_{CTL}=3.3\text{V}$	-	40	80	$\mu\text{A}$

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## ■ ELECTRICAL CHARACTERISTICS 2 (LNA High Gain Mode 1)

(General Conditions:  $V_{DD}=V_{INV}=2.8V$ ,  $V_{CTL}=1.85V$ ,  $f_{RF}=880MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 1)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain_1(1)	Gain_1(1)		13.5	15.0	17.0	dB
Noise figure_1(1)	NF_1(1)	Exclude PCB & connector losses (IN: 0.04dB)	-	1.4	1.8	dB
1dB gain compression output power_1(1)	P-1dB_1(1)		+4	+9	-	dBm
3rd order Input Intercept Point_1(1)	IIP3_1(1)	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{in}=-25dBm$	+8	+11	-	dBm
RF IN VSWR_1(1)	VSWR <sub>i</sub> _1(1)		-	1.5	2.0	
RF OUT VSWR_1(1)	VSWR <sub>o</sub> _1(1)		-	1.5	2.0	

## ■ ELECTRICAL CHARACTERISTICS 3 (LNA Low Gain Mode 1)

(General Conditions:  $V_{DD}=V_{INV}=2.8V$ ,  $V_{CTL}=0V$ ,  $f_{RF}=880MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 1)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain_1(2)	Gain_1(2)		-4.0	-2.5	0	dB
Noise figure_1(2)	NF_1(2)	Exclude PCB & connector losses (IN: 0.04dB)	-	2.5	5.0	dB
1dB gain compression output power_1(2)	P-1dB_1(2)		+1	+8	-	dBm
3rd order Input Intercept Point_1(2)	IIP3_1(2)	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{in}=-12dBm$	+15	+19	-	dBm
RF IN VSWR_1(2)	VSWR <sub>i</sub> _1(2)		-	2.3	2.7	
RF OUT VSWR_1(2)	VSWR <sub>o</sub> _1(2)		-	1.8	2.1	

## ■ ELECTRICAL CHARACTERISTICS 4 (LNA High Gain Mode 2)

(General Conditions:  $V_{DD}=V_{INV}=V_{CTL}=3.3V$ ,  $f_{RF}=760MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 2)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small signal gain _2(1)	Gain_2(1)		13.5	16.0	18.5	dB
Noise figure _2(1)	NF_2(1)	Exclude PCB & connector losses (IN: 0.04dB)	-	1.2	1.8	dB
1dB gain compression output power _2(1)	P-1dB_2(1)		+4.0	+11.0	-	dBm
Output Power	$P_{out}$	$P_{in}=-40\sim+22dBm$	-	-	+15.5	dBm
3rd order Input Intercept Point _2(1)	IIP3_2(1)	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{in}=-25dBm$	+6.0	+8.0	-	dBm
Gain Settling time _2(1)	$Ts_{(1)}$	Low gain to high gain mode to be within 1dB of the final gain	-	0.5	2.5	$\mu s$
RF IN VSWR _2(1)	$VSWR_i_{(1)}$		-	1.6	2.0	
RF OUT VSWR _2(1)	$VSWR_o_{(1)}$		-	1.3	2.0	

## ■ ELECTRICAL CHARACTERISTICS 5 (LNA Low Gain Mode 2)

(General Conditions:  $V_{DD}=V_{INV}=3.3V$ ,  $V_{CTL}=0V$ ,  $f_{RF}=760MHz$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 2)

項目	記号	条件	最小	標準	最大	単位
Small signal gain _2(2)	Gain_2(2)		-4.5	-2.5	0	dB
Noise figure _2(2)	NF_2(2)	Exclude PCB & connector losses (IN: 0.04dB)	-	2.5	5.5	dB
1dB gain compression output power _2(2)	P-1dB_2(2)		+1.0	+7.5	-	dBm
3rd order Input Intercept Point _2(2)	IIP3_2(2)	$f1=f_{RF}$ , $f2=f_{RF}+100kHz$ , $P_{in}=-12dBm$	+15.0	+21.0	-	dBm
Gain Settling time _2(2)	$Ts_{(2)}$	High gain to low gain mode to be within 1dB of the final gain	-	1.0	2.5	$\mu s$
RF IN VSWR _2(2)	$VSWR_i_{(2)}$		-	2.1	3.0	
RF OUT VSWR _2(2)	$VSWR_o_{(2)}$		-	1.6	2.1	

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## ■ TERMINAL INFORMATION

No.	SYMBOL	DESCRIPTION
1	VINV	Supply voltage terminal for internal logic circuit (inverter). Please place a bypass capacitor between this and GND for avoiding RF noise from outside.
2	GND	Ground terminal.
3	RFOUT	RF signal comes out from this terminal, and goes through an external matching circuit connected to this. Inductor L4 as shown in the application circuit is a part of an external matching circuit, and also provide DC power to LNA. Capacitor C2 as shown in the application circuit is a bypass capacitor.
4	GND	Ground terminal.
5	RFIN	RF input terminal. The RF signal is input through external matching circuit connected to this terminal. A DC blocking capacitor is not required.
6	GND	Ground terminal.
7	VCTL	Control port. A logic control signal is required to select High or Low gain mode of LNA. This terminal is set to more than +1.8V of logical high level for High gain mode of LNA, and set to 0~+0.3V of logical low level for Low gain mode.
8	GND	Ground terminal.

### CAUTION

- 1) Ground terminal (No.2, 4, 6, 8) should be connected to the ground plane as close as possible for excellent RF performance, because distance to GND makes parasitic inductance.

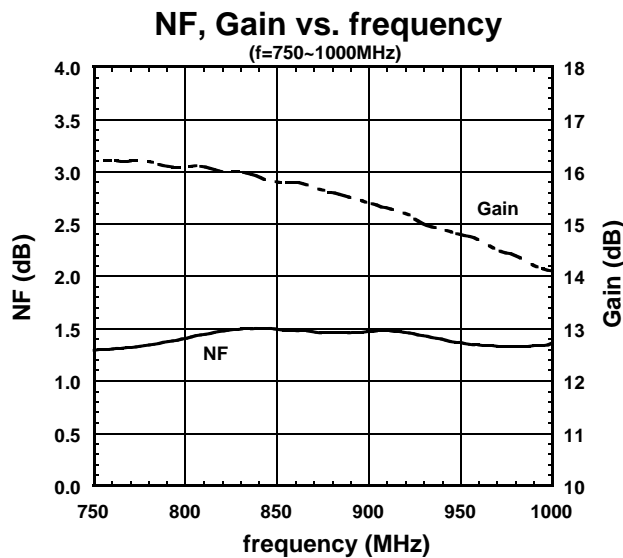
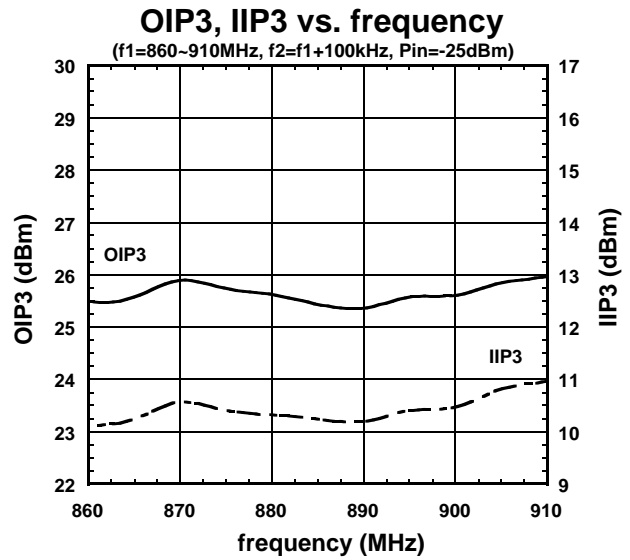
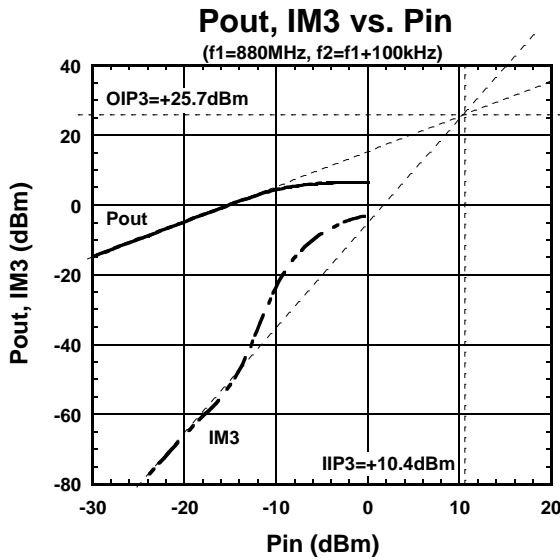
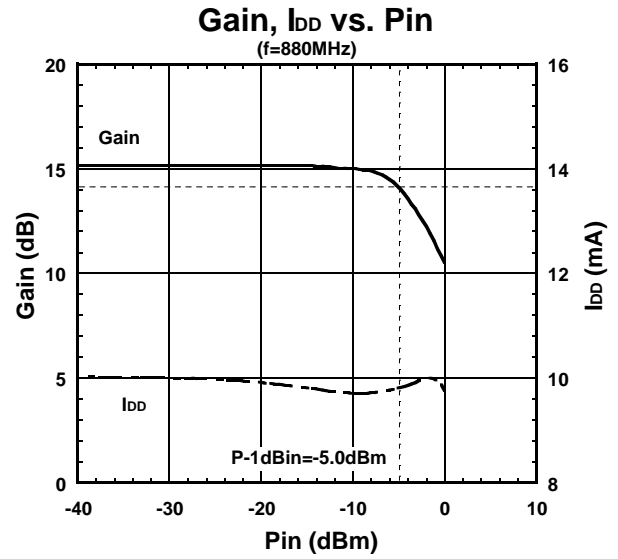
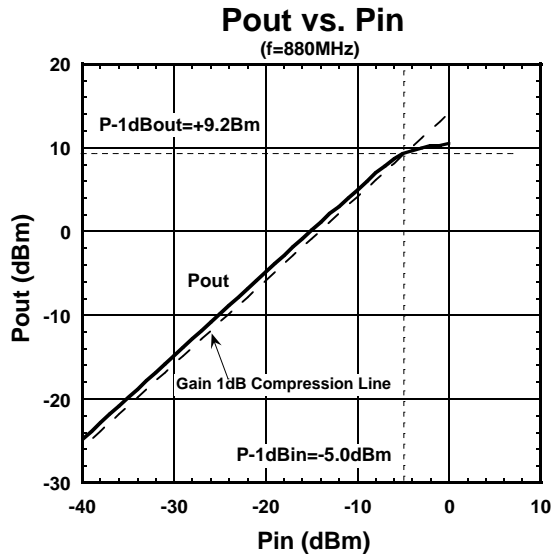
## ■ TRUTH TABLE

"H"= $V_{CTL}(H)$ , "L"= $V_{CTL}(L)$

$V_{CTL}$	Gain Mode	LNA
L	Low	bypass
H	High	pass

## ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 1)

(General Conditions:  $T_a=+25^\circ\text{C}$ ,  $f_{\text{RF}}=880\text{MHz}$ ,  $V_{\text{DD}}=V_{\text{INV}}=2.8\text{V}$ ,  $V_{\text{CTL}}=1.85\text{V}$ ,  $Z_s=Z_L=50\Omega$ , with application circuit 1)

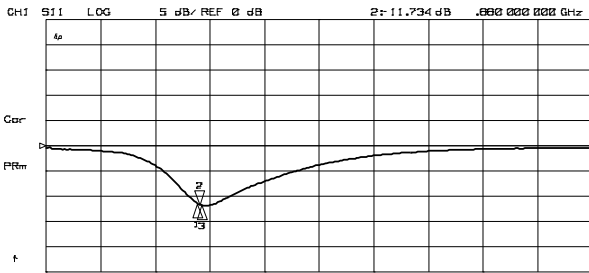


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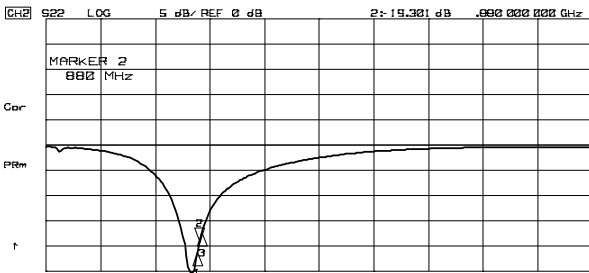
## ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 1)

(General Conditions:

$T_a = +25^\circ\text{C}$ ,  $f_{RF} = 880\text{MHz}$ ,  $V_{DD} = V_{INV} = 2.8\text{V}$ ,  $V_{CTL} = 1.85\text{V}$ ,  $Z_s = Z_l = 50\Omega$ , with application circuit 1)

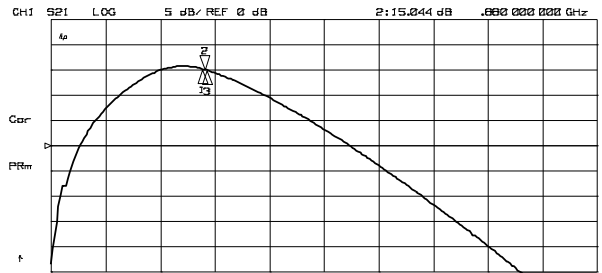


CH1 Markers  
 1: 11.520 dB  
 869.000 MHz  
 3: 11.881 dB  
 894.000 MHz

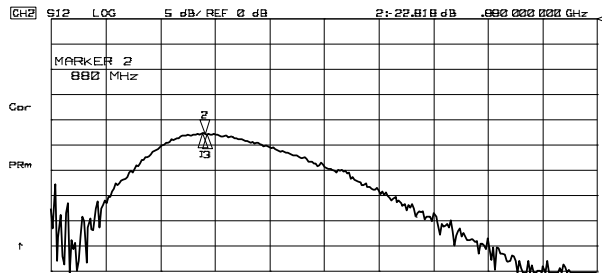


CH2 Markers  
 1: 21.276 dB  
 869.000 MHz  
 3: 17.321 dB  
 894.000 MHz

S11, S22

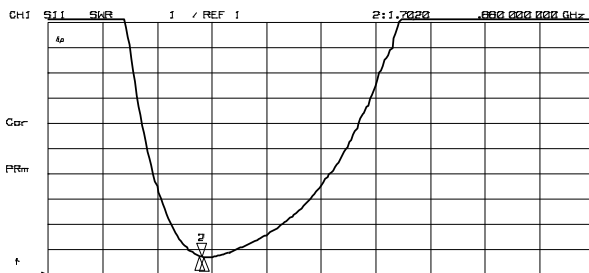


CH1 Markers  
 1: 15.139 dB  
 869.000 MHz  
 3: 14.887 dB  
 894.000 MHz

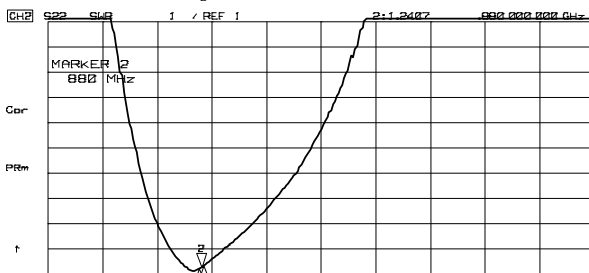


CH2 Markers  
 1: 22.753 dB  
 869.000 MHz  
 3: 22.974 dB  
 894.000 MHz

S21, S12

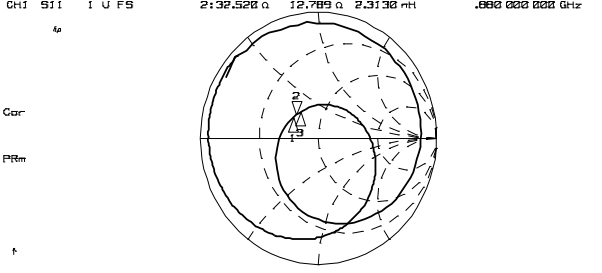


CH1 Markers  
 1: 1.7288  
 869.000 MHz  
 3: 1.6811  
 894.000 MHz

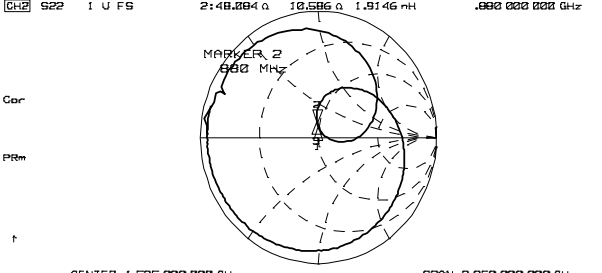


CH2 Markers  
 1: 1.1948  
 869.000 MHz  
 3: 1.3148  
 894.000 MHz

VSWR



CH1 Markers  
 1: 31.229 Ω  
 10.767 Ω  
 869.000 MHz  
 3: 34.457 Ω  
 15.203 Ω  
 894.000 MHz



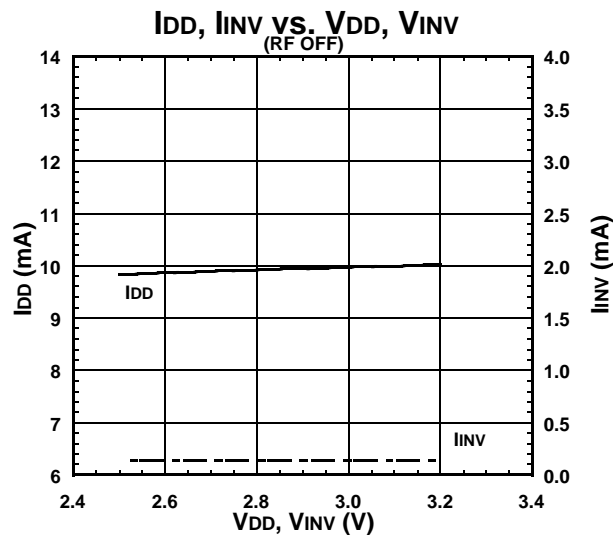
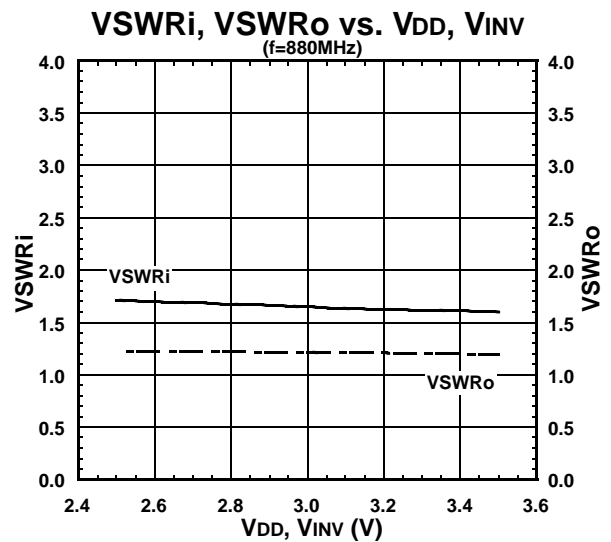
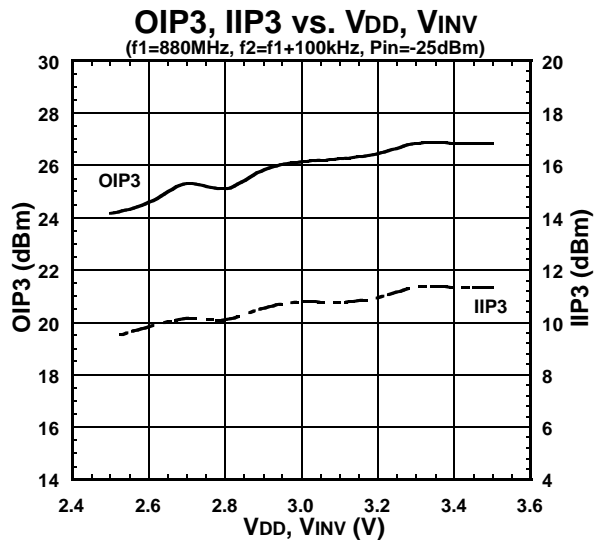
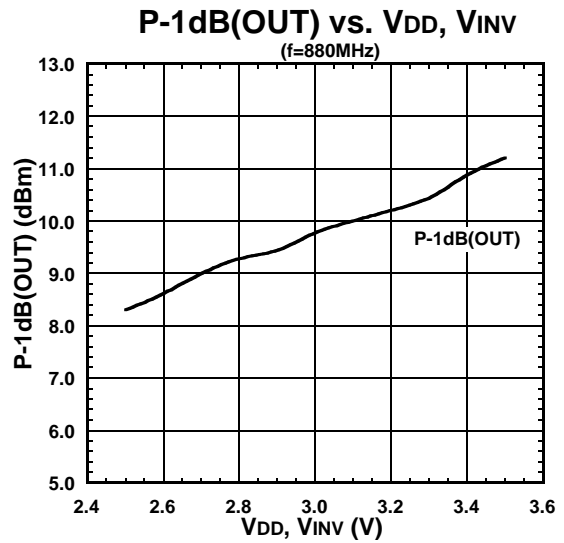
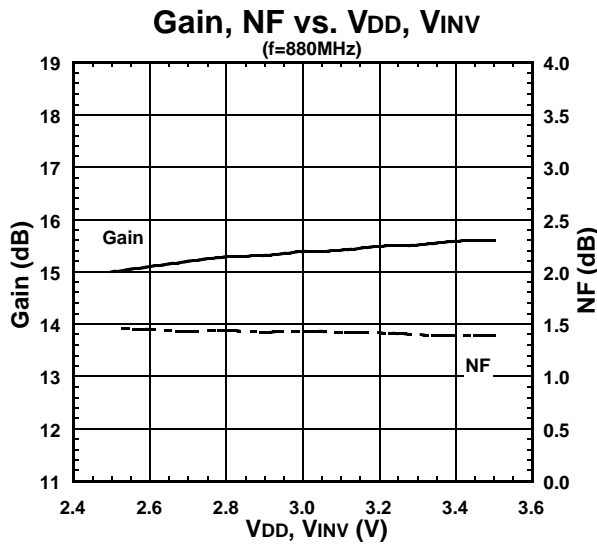
CH2 Markers  
 1: 49.250 Ω  
 8.6309 Ω  
 869.000 MHz  
 3: 47.146 Ω  
 13.000 Ω  
 894.000 MHz

Zin, Zout

## ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 1)

(General Conditions:

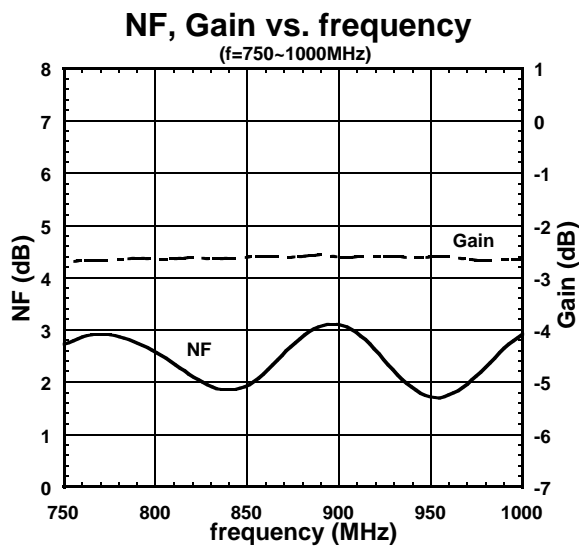
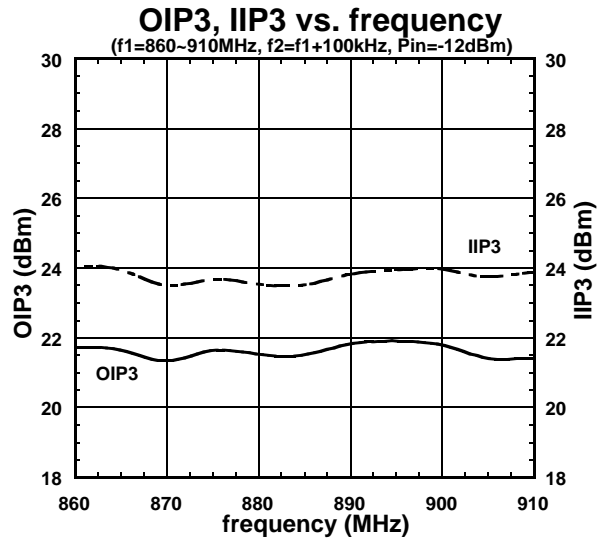
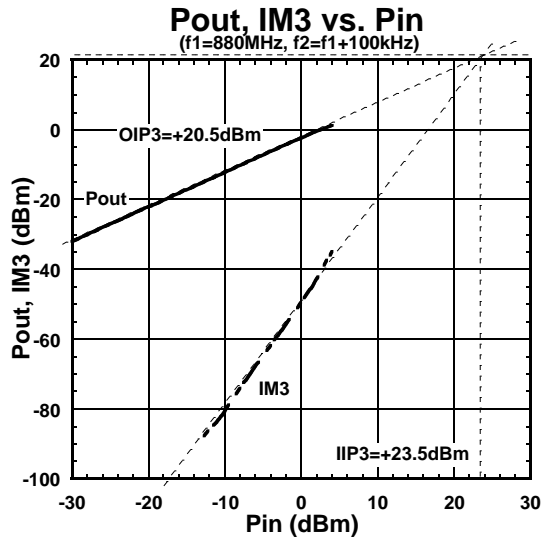
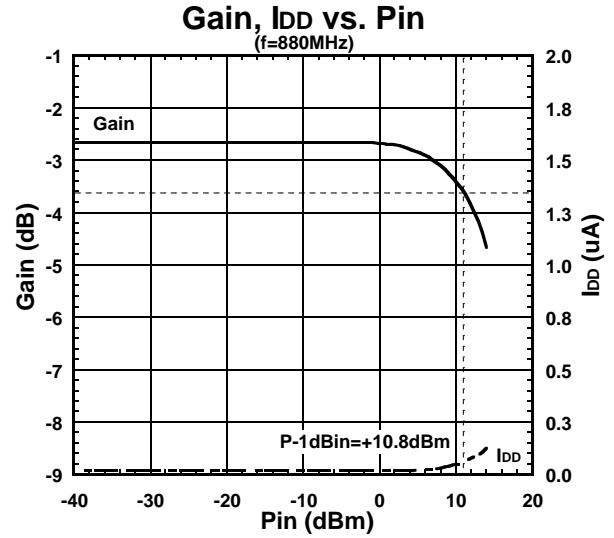
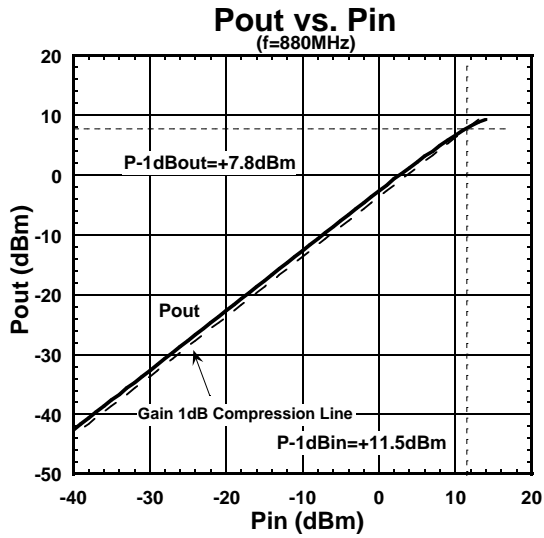
$T_a = +25^\circ\text{C}$ ,  $f_{RF} = 880\text{MHz}$ ,  $V_{DD} = V_{INV} = 2.8\text{V}$ ,  $V_{CTL} = 1.85\text{V}$ ,  $Z_s = Z_l = 50\Omega$ , with application circuit 1)



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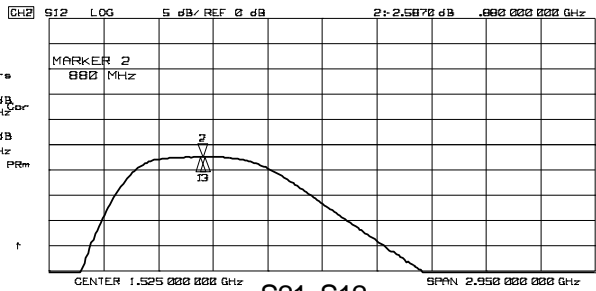
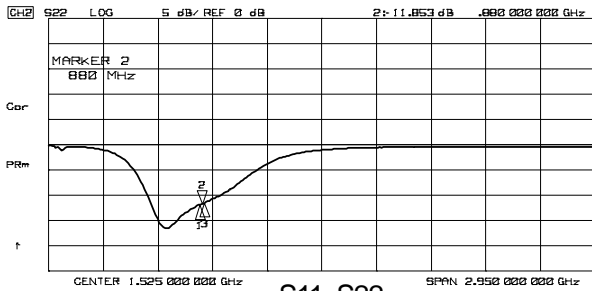
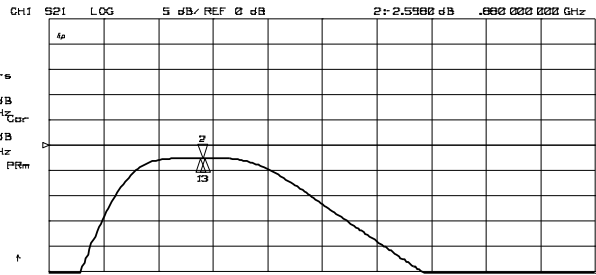
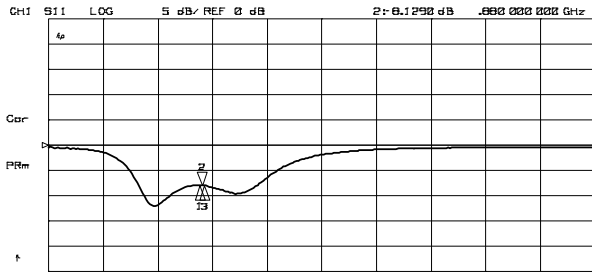
## ■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 1)

(General Conditions:  $T_a=+25^{\circ}\text{C}$ ,  $f_{\text{RF}}=880\text{MHz}$ ,  $V_{\text{DD}}=V_{\text{INV}}=2.8\text{V}$ ,  $V_{\text{CTL}}=0\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 1)



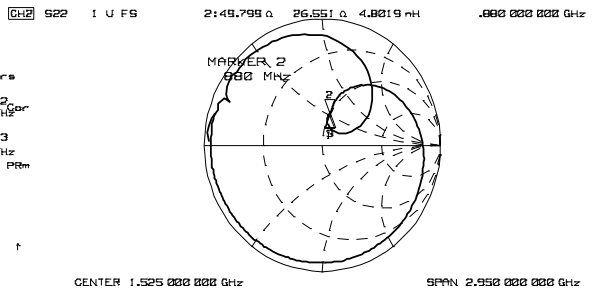
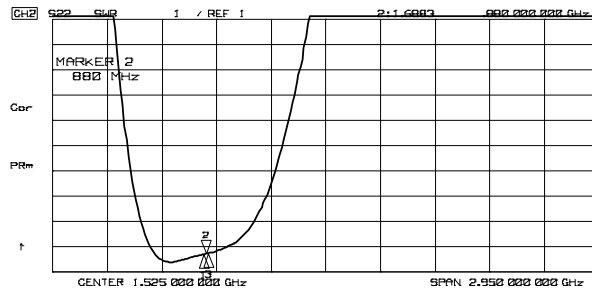
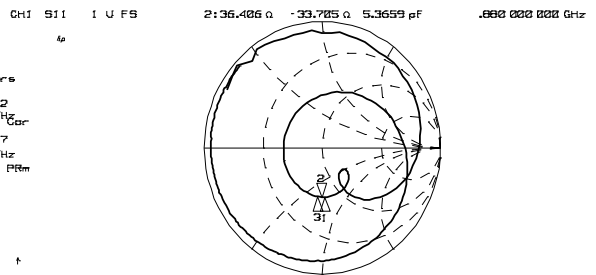
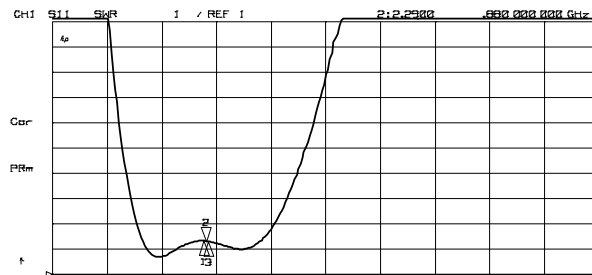
## ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 1)

(General Conditions:  $T_a=+25^{\circ}\text{C}$ ,  $f_{RF}=880\text{MHz}$ ,  $V_{DD}=V_{INV}=2.8\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 1)



S11, S22

S21, S12



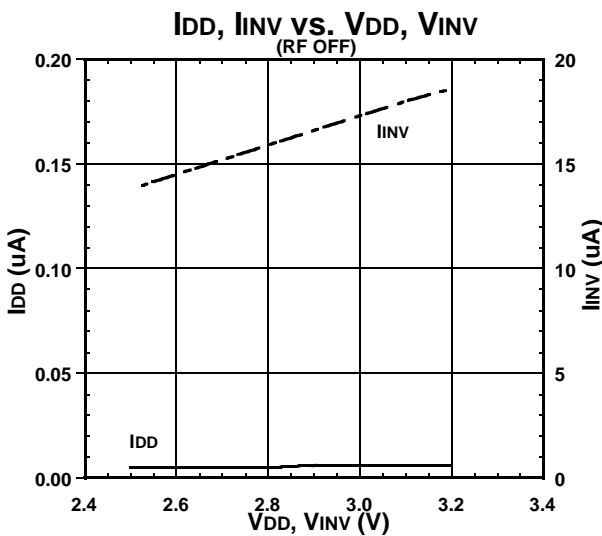
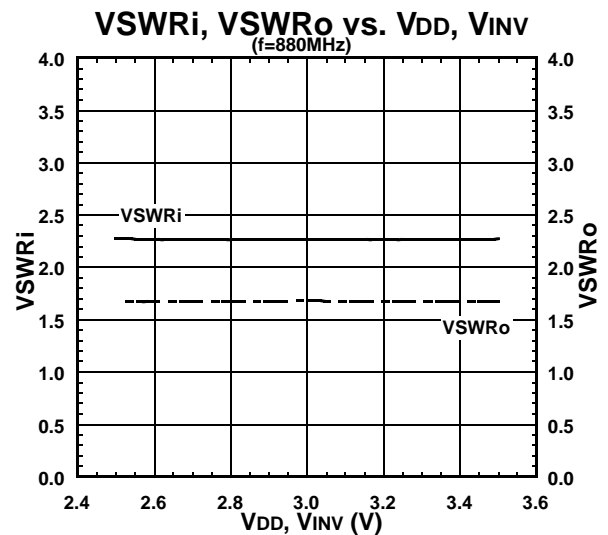
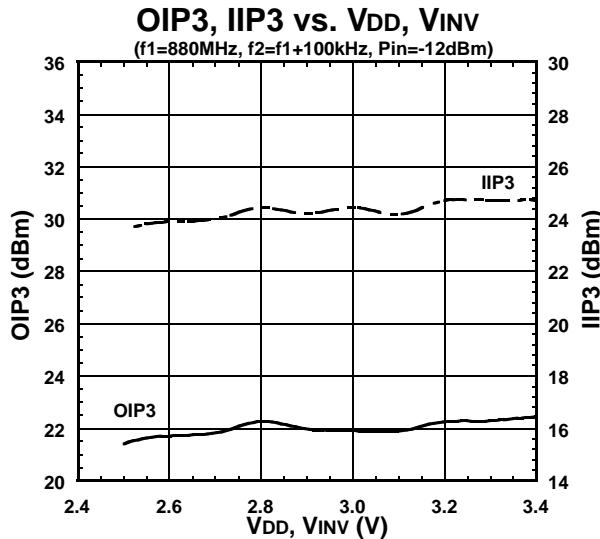
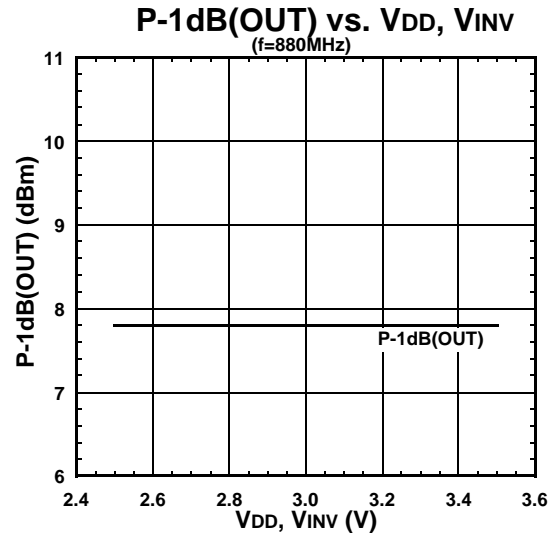
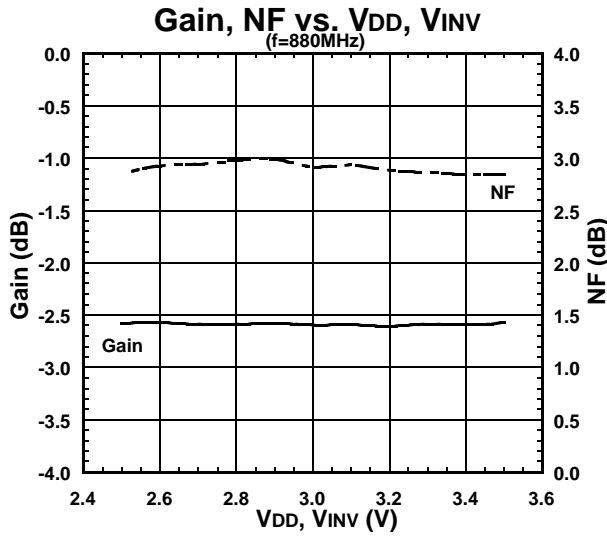
VSWR

Zin, Zout

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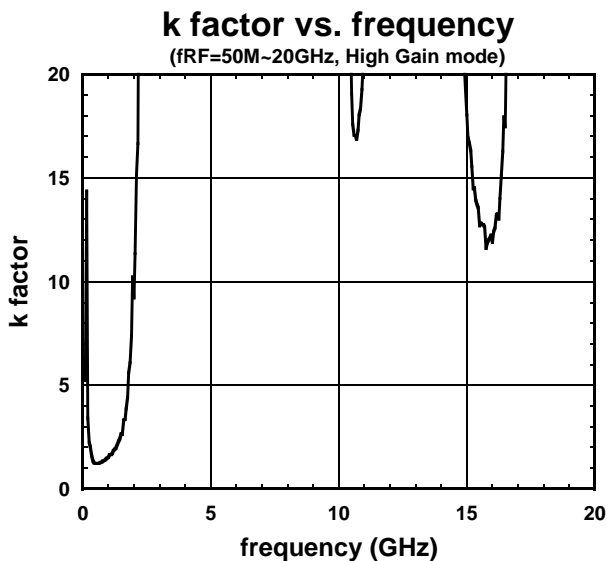
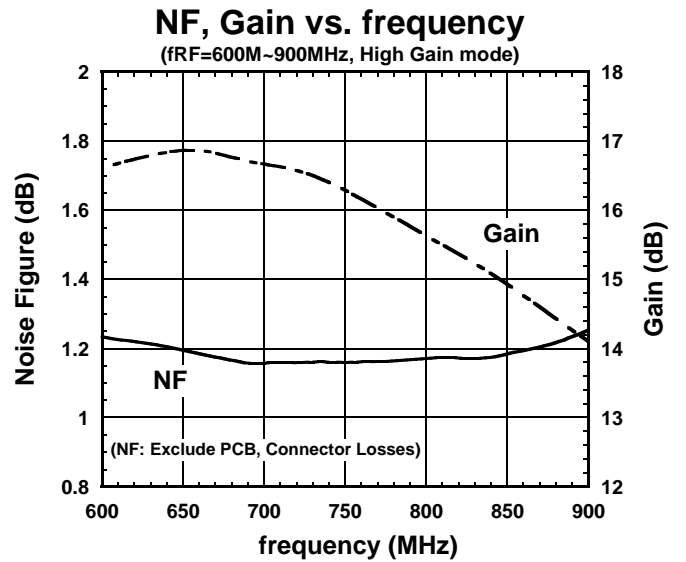
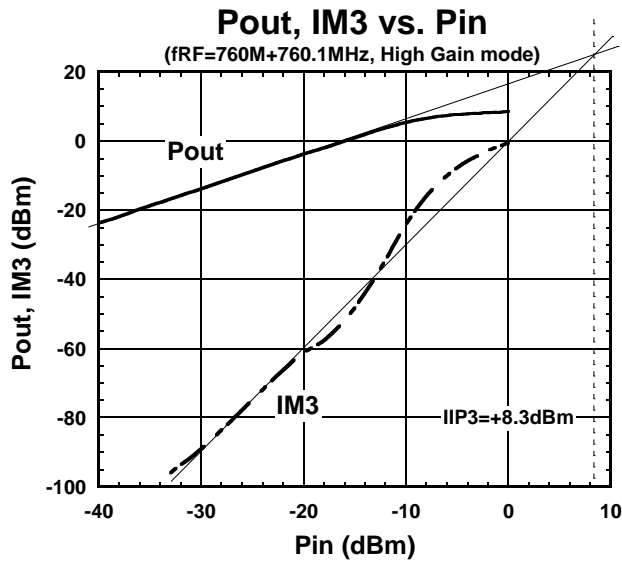
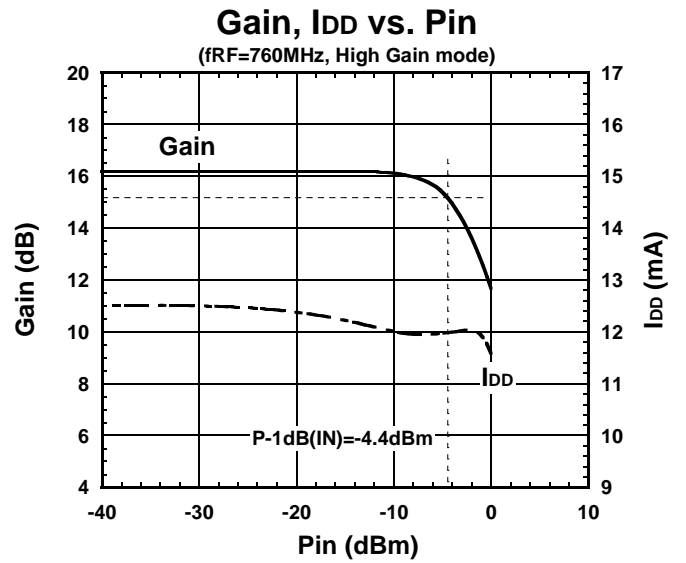
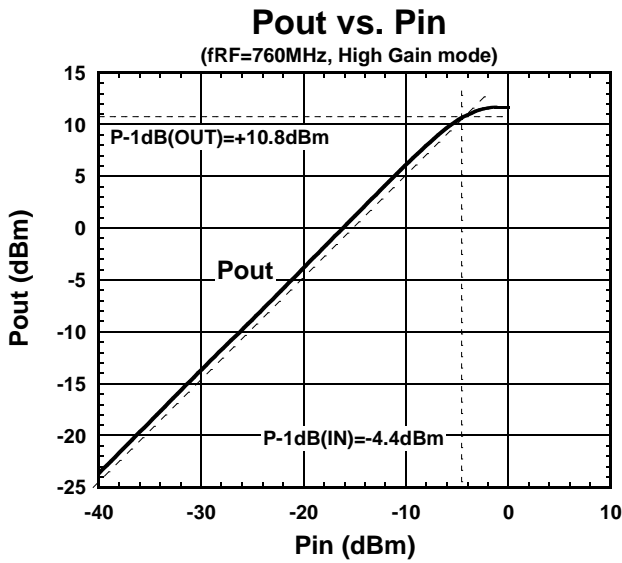
## ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 1)

(General Conditions:  $T_a=+25^\circ\text{C}$ ,  $f_{RF}=880\text{MHz}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 1)



## ■ ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 2)

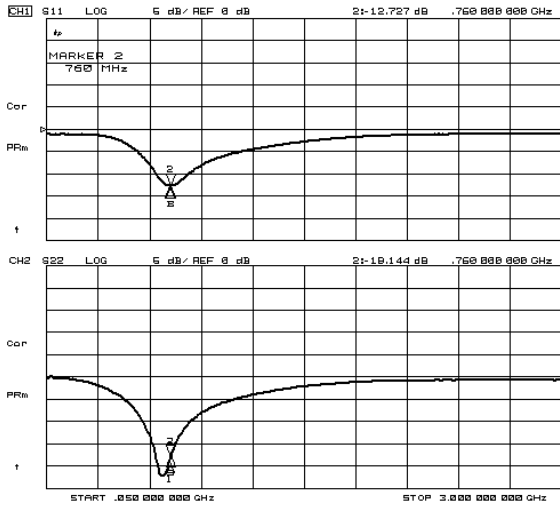
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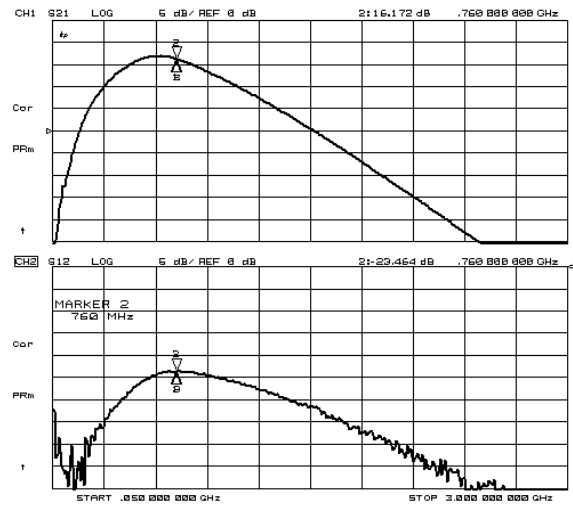
# NJG1127HB6

## ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 2)

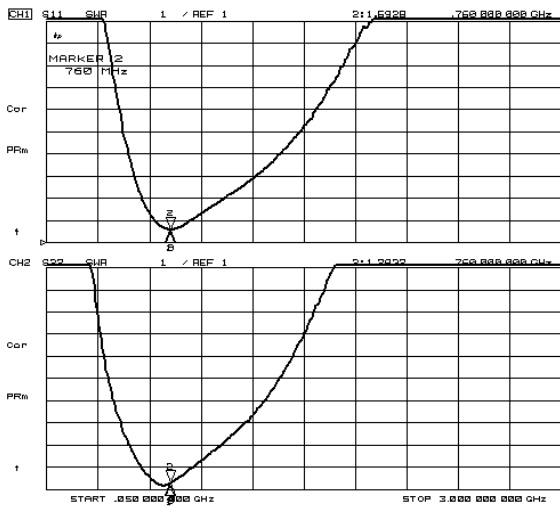
(General Conditions:  $T_a=+25^{\circ}\text{C}$ ,  $f_{RF}=760\text{MHz}$ ,  $V_{DD}=V_{INV}=V_{CTL}=3.3\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 2)



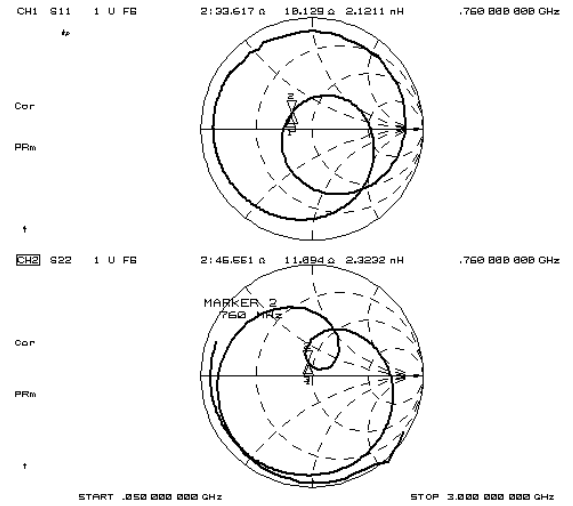
S11, S22



S21, S12



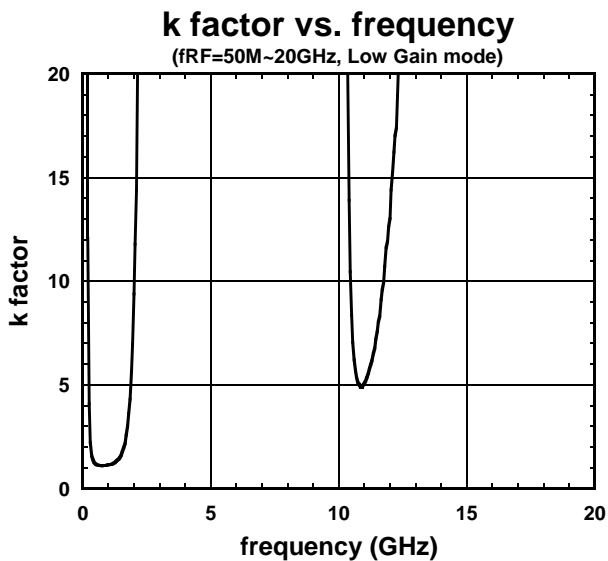
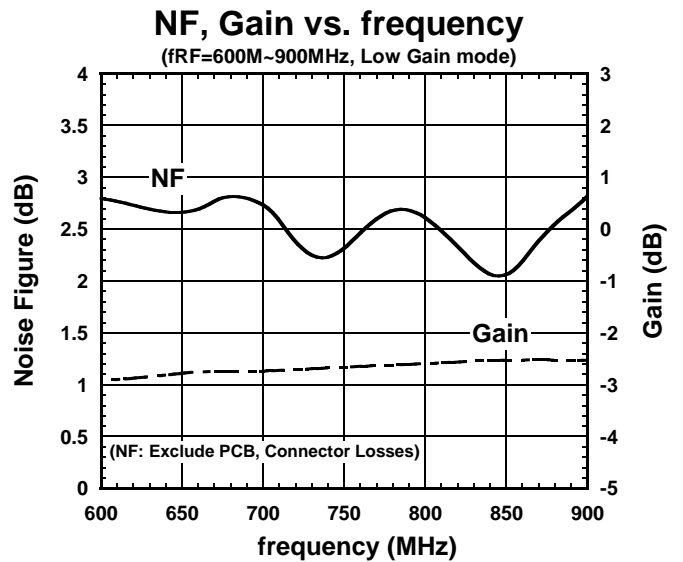
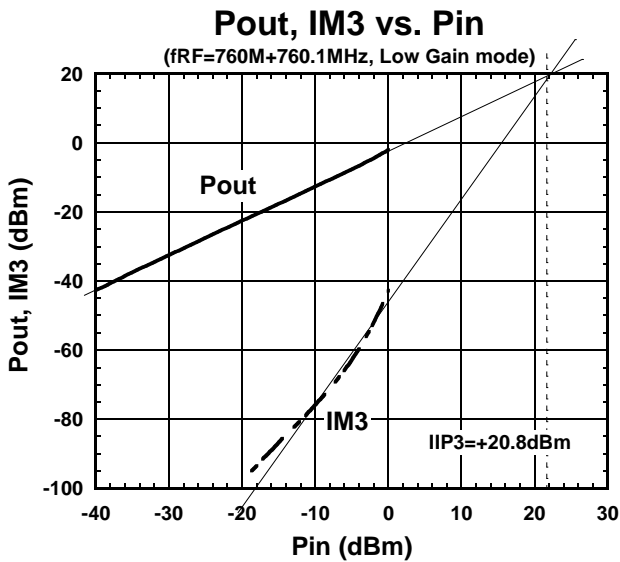
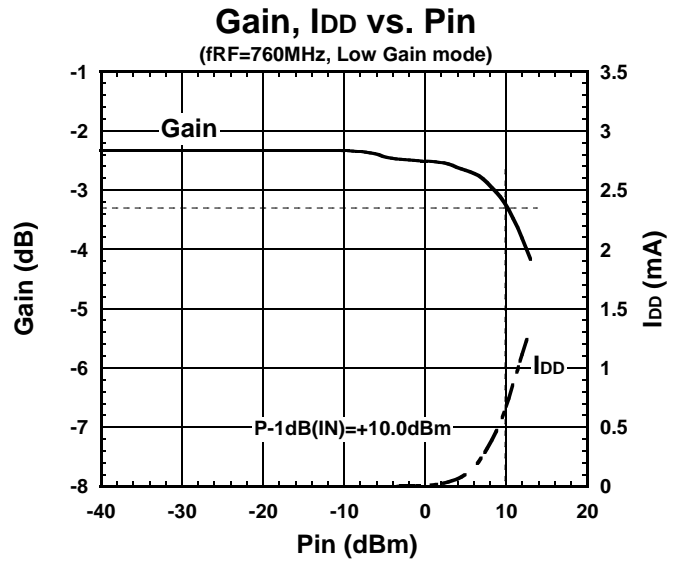
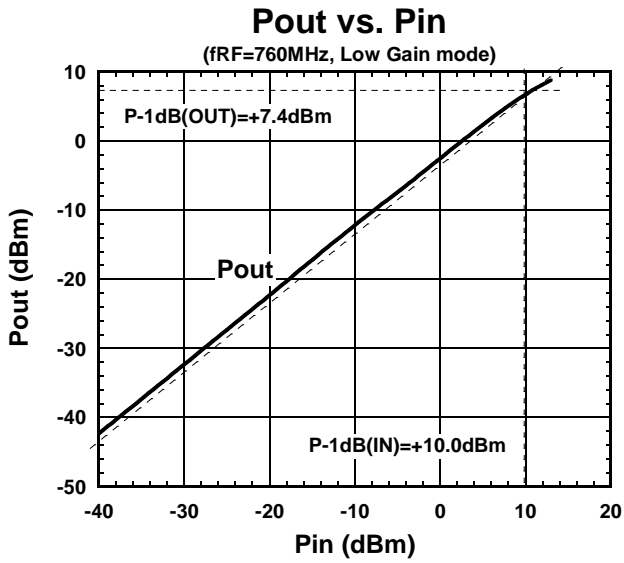
VSWR



Zin, Zout

## ■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 2)

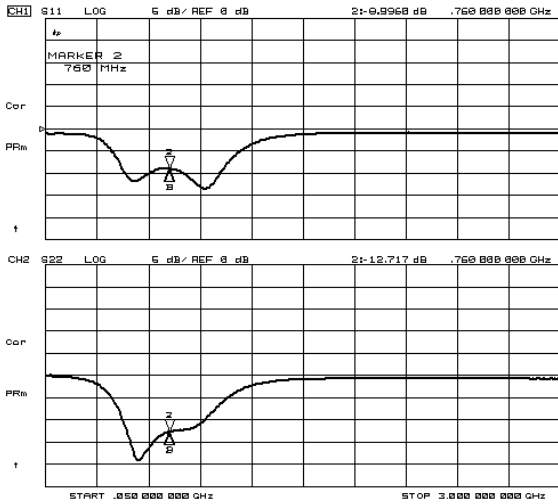
(General Conditions:  $T_a=+25^\circ\text{C}$ ,  $f_{RF}=760\text{MHz}$ ,  $V_{DD}=V_{INV}=3.3\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_S=Z_L=50\Omega$ , with application circuit 2)



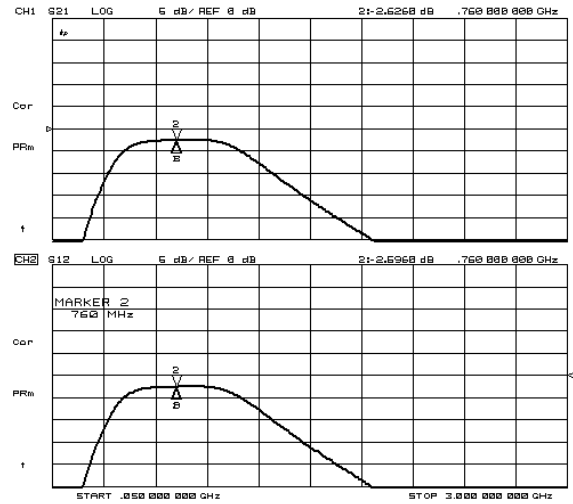
# NJG1127HB6

## ■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 2)

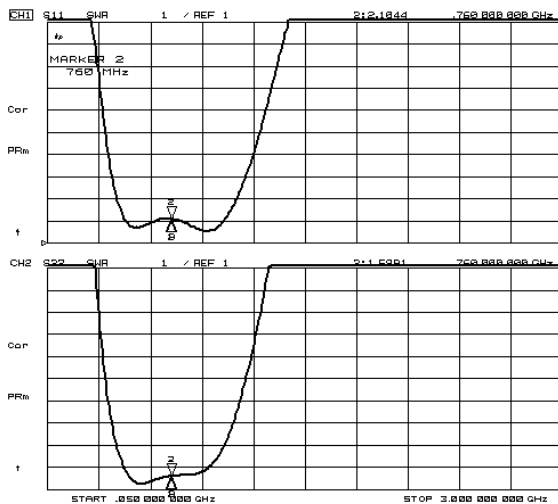
(General Conditions:  $T_a=+25^{\circ}\text{C}$ ,  $f_{RF}=760\text{MHz}$ ,  $V_{DD}=V_{INV}=3.3\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 2)



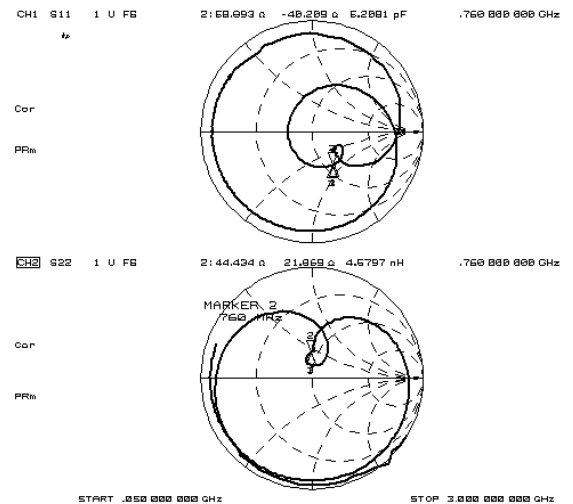
S11, S22



S21, S12



VSWR

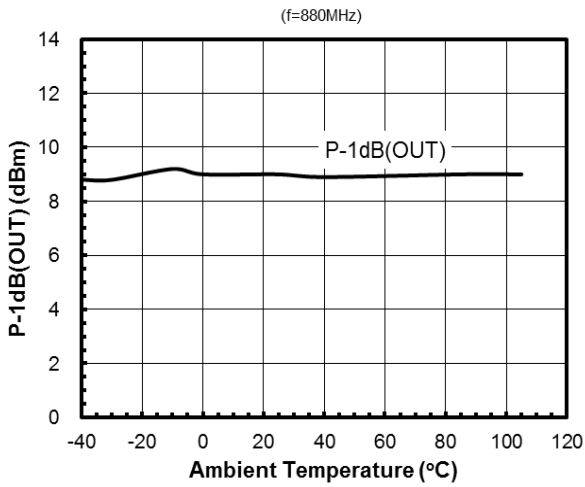


Zin, Zout

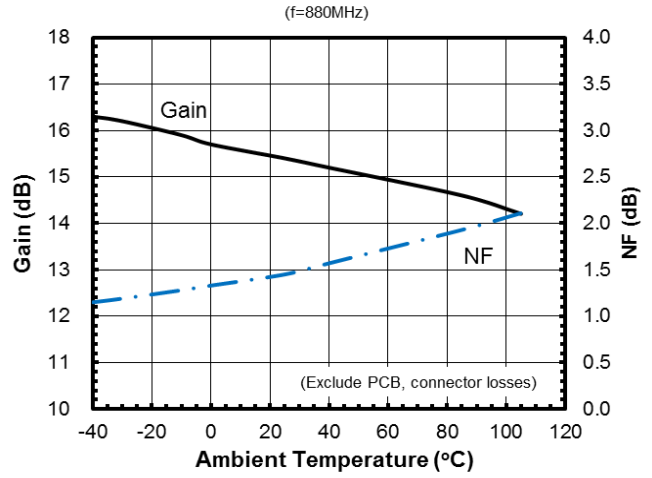
## ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 1)

(General Conditions:  $f_{RF}=880\text{MHz}$ ,  $V_{DD}=V_{INV}=2.8\text{V}$ ,  $V_{CTL}=1.85\text{V}$ ,  $Z_S=Z_L=50\Omega$ , with application circuit 1)

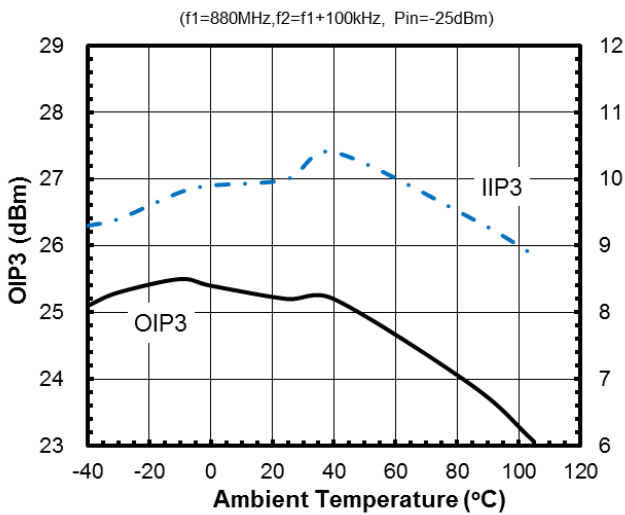
**P-1dB(OUT) vs. Ambient Temperature**



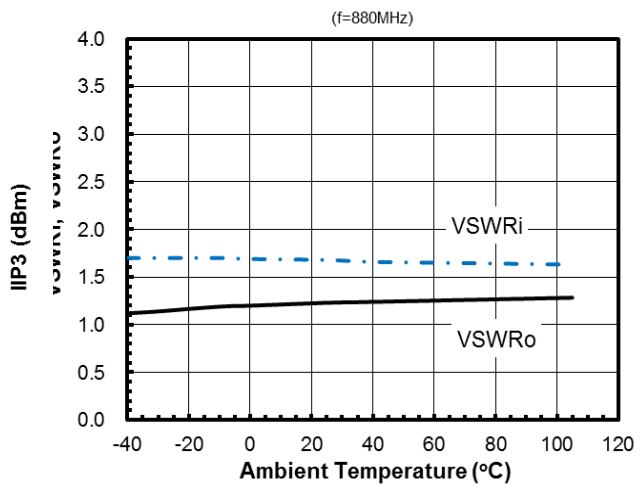
**Gain, NF vs. Ambient Temperature**



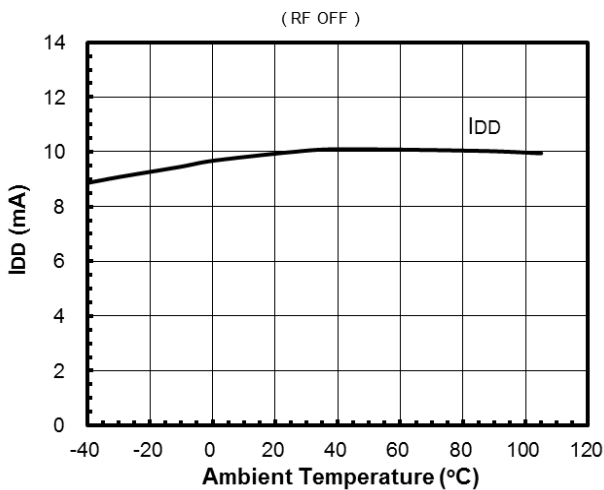
**OIP3, IIP3 vs. Ambient Temperature**



**VSWRi, VSWRo vs. Ambient Temperature**



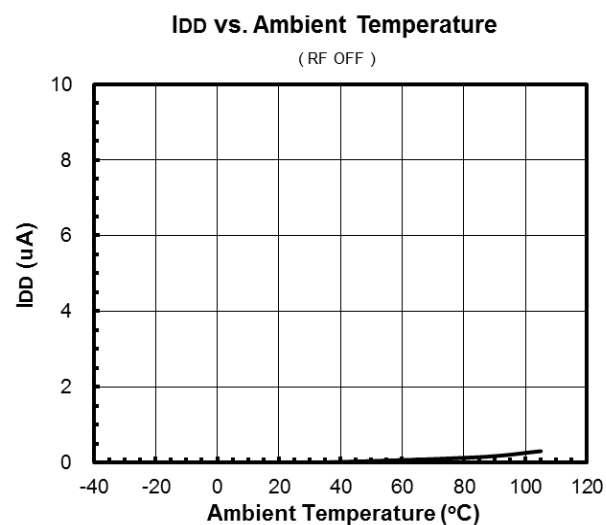
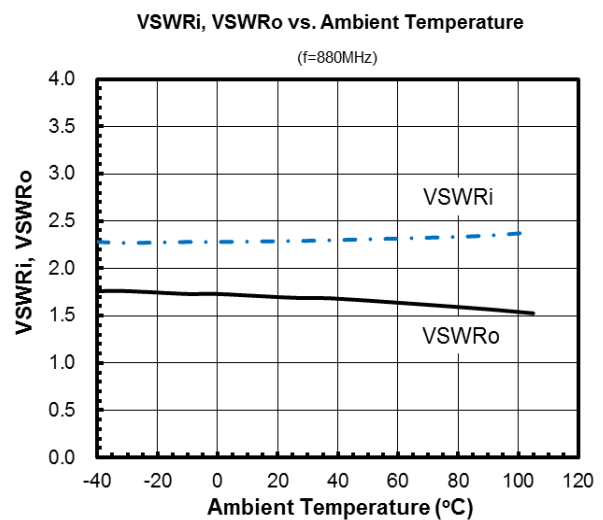
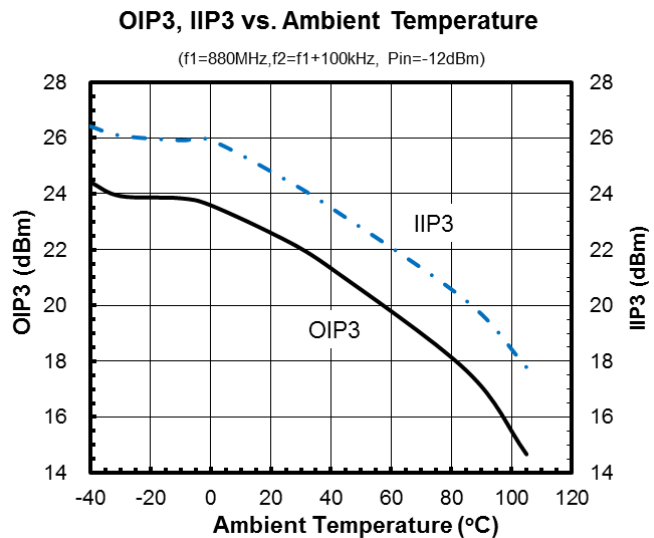
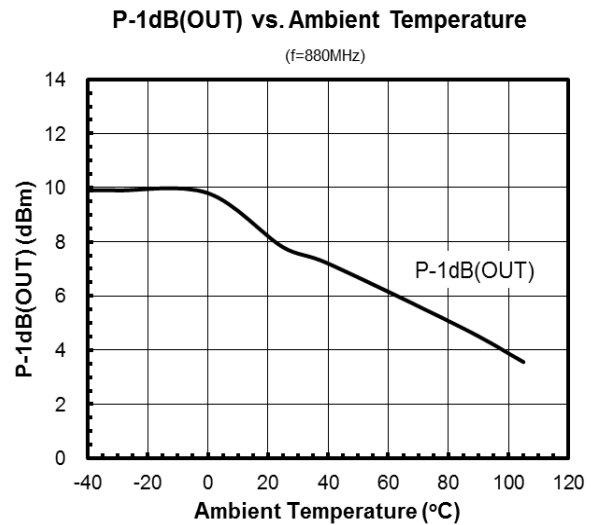
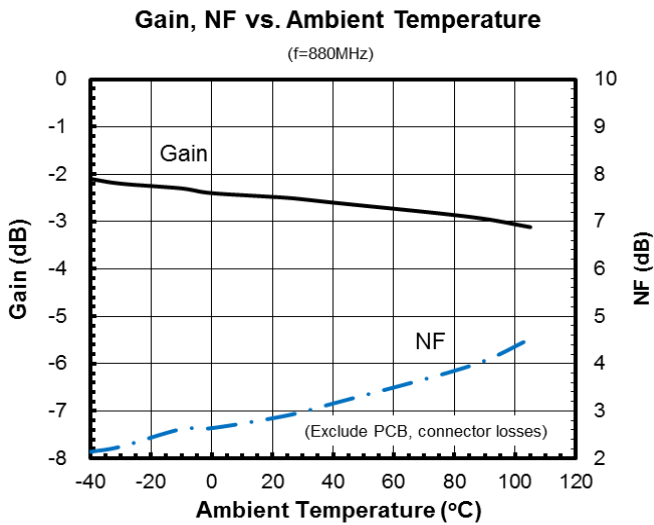
**IDD vs. Ambient Temperature**



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## ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 1)

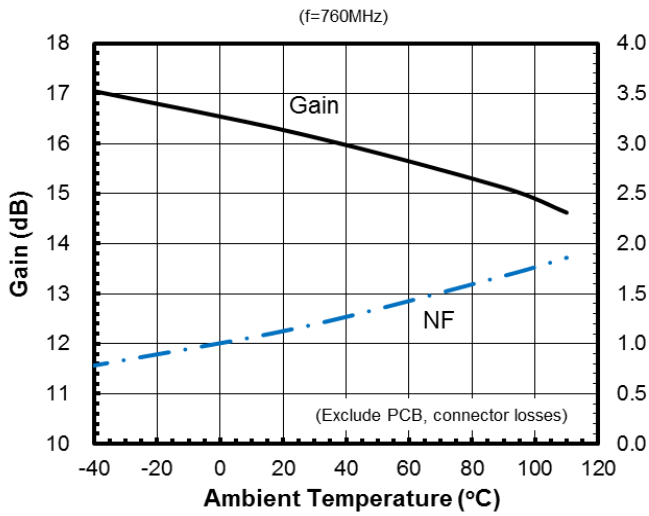
(General Conditions:  $f_{RF}=880\text{MHz}$ ,  $V_{DD}=V_{INV}=2.8\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 1)



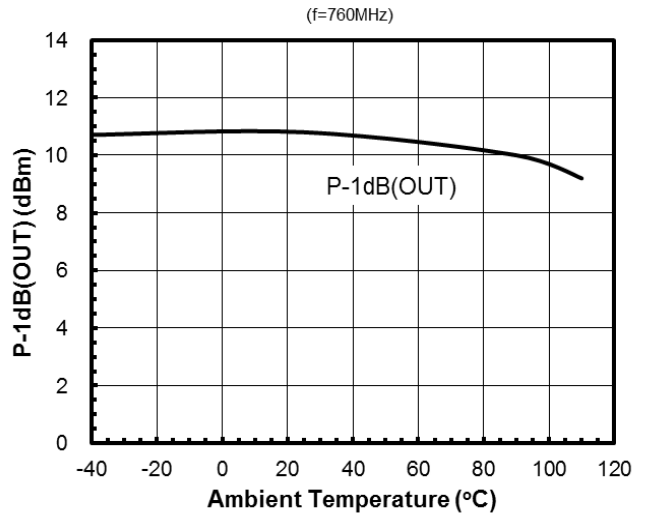
## ■ ELECTRICAL CHARACTERISTICS (LNA High Gain Mode 2)

(General Conditions:  $f_{RF}=760\text{MHz}$ ,  $V_{DD}=V_{INV}=V_{CTL}=3.3\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 2)

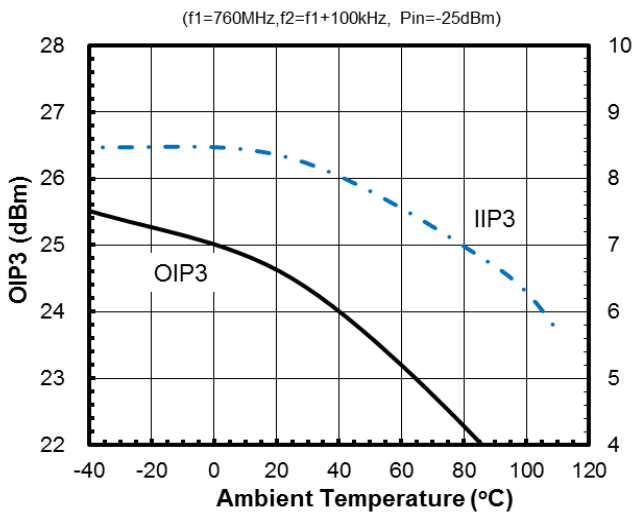
**Gain, NF vs. Ambient Temperature**



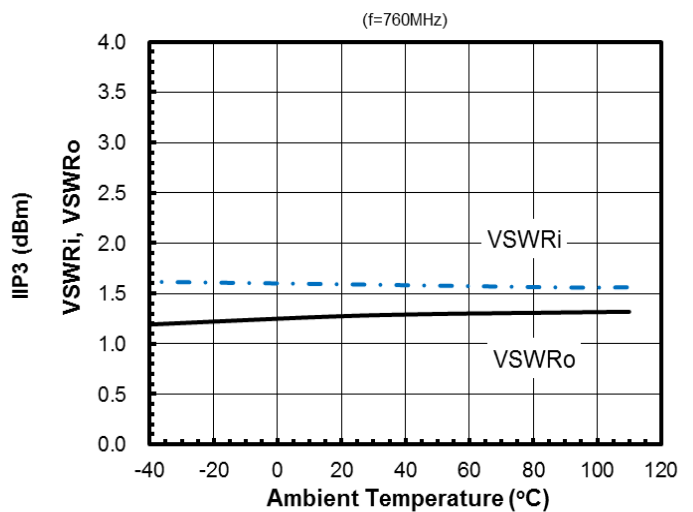
**P-1dB(OUT) vs. Ambient Temperature**



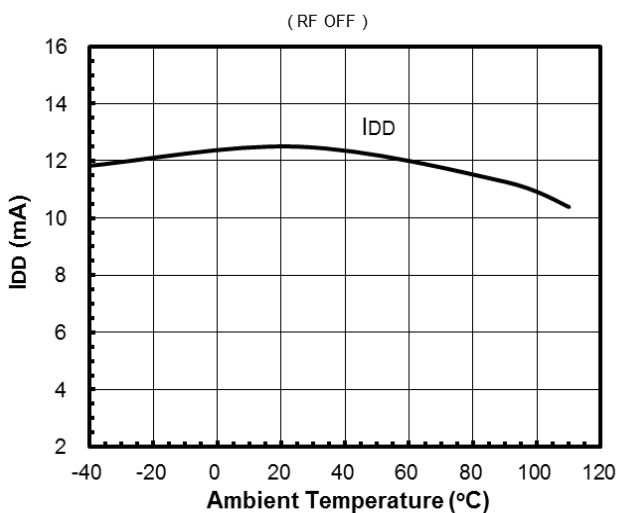
**OIP3, IIP3 vs. Ambient Temperature**



**VSWRi, VSWRo vs. Ambient Temperature**



**IDD vs. Ambient Temperature**



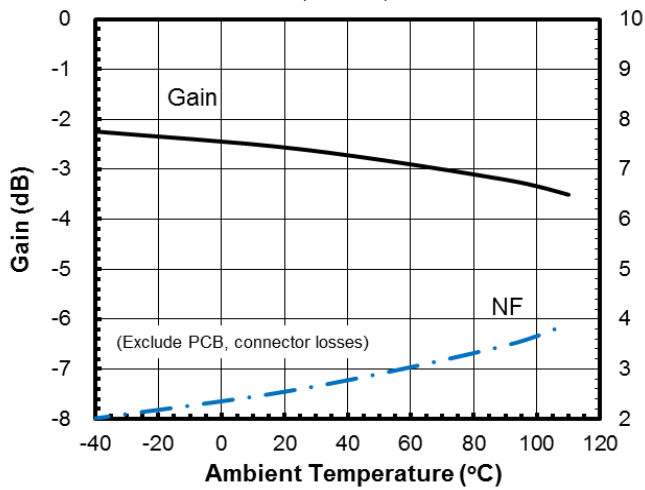
# NJG1127HB6

## ■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode 2)

(General Conditions:  $f_{RF}=760\text{MHz}$ ,  $V_{DD}=V_{INV}=3.3\text{V}$ ,  $V_{CTL}=0\text{V}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit 2)

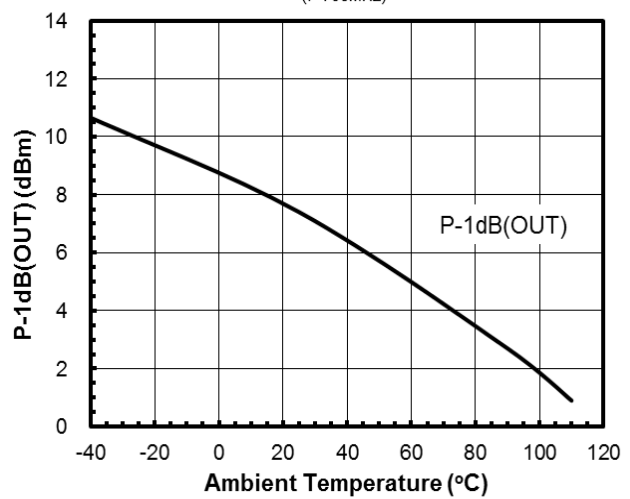
**Gain, NF vs. Ambient Temperature**

( $f=760\text{MHz}$ )



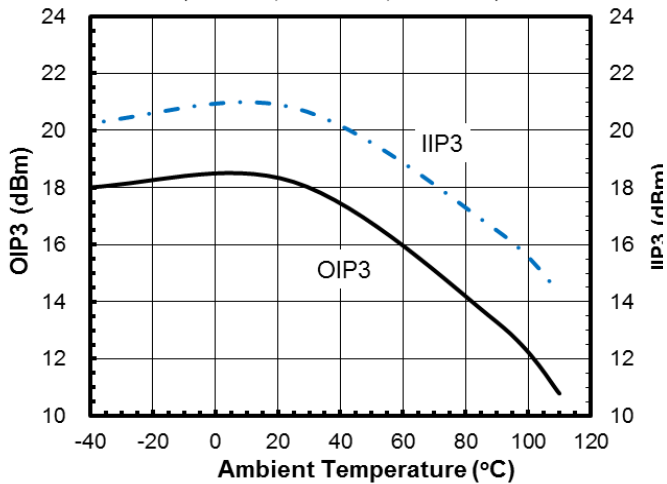
**P-1dB(OUT) vs. Ambient Temperature**

( $f=760\text{MHz}$ )



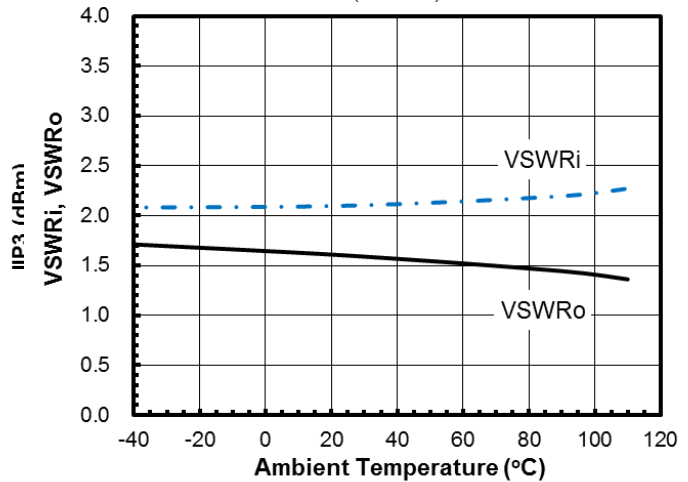
**OIP3, IIP3 vs. Ambient Temperature**

( $f_1=760\text{MHz}$ ,  $f_2=f_1+100\text{kHz}$ ,  $P_{in}=-12\text{dBm}$ )



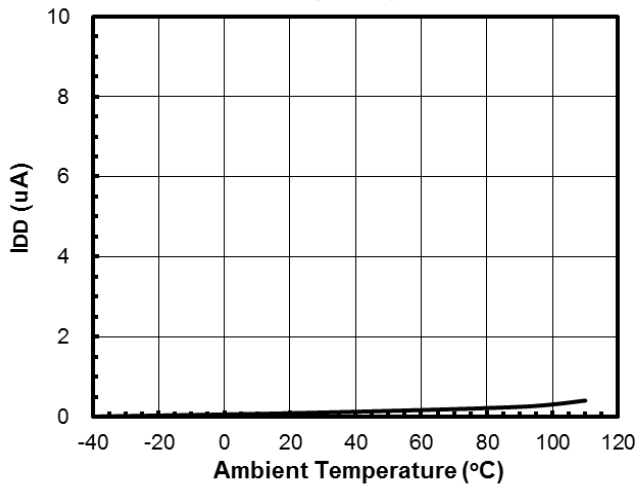
**VSWRi, VSWRo vs. Ambient Temperature**

( $f=760\text{MHz}$ )

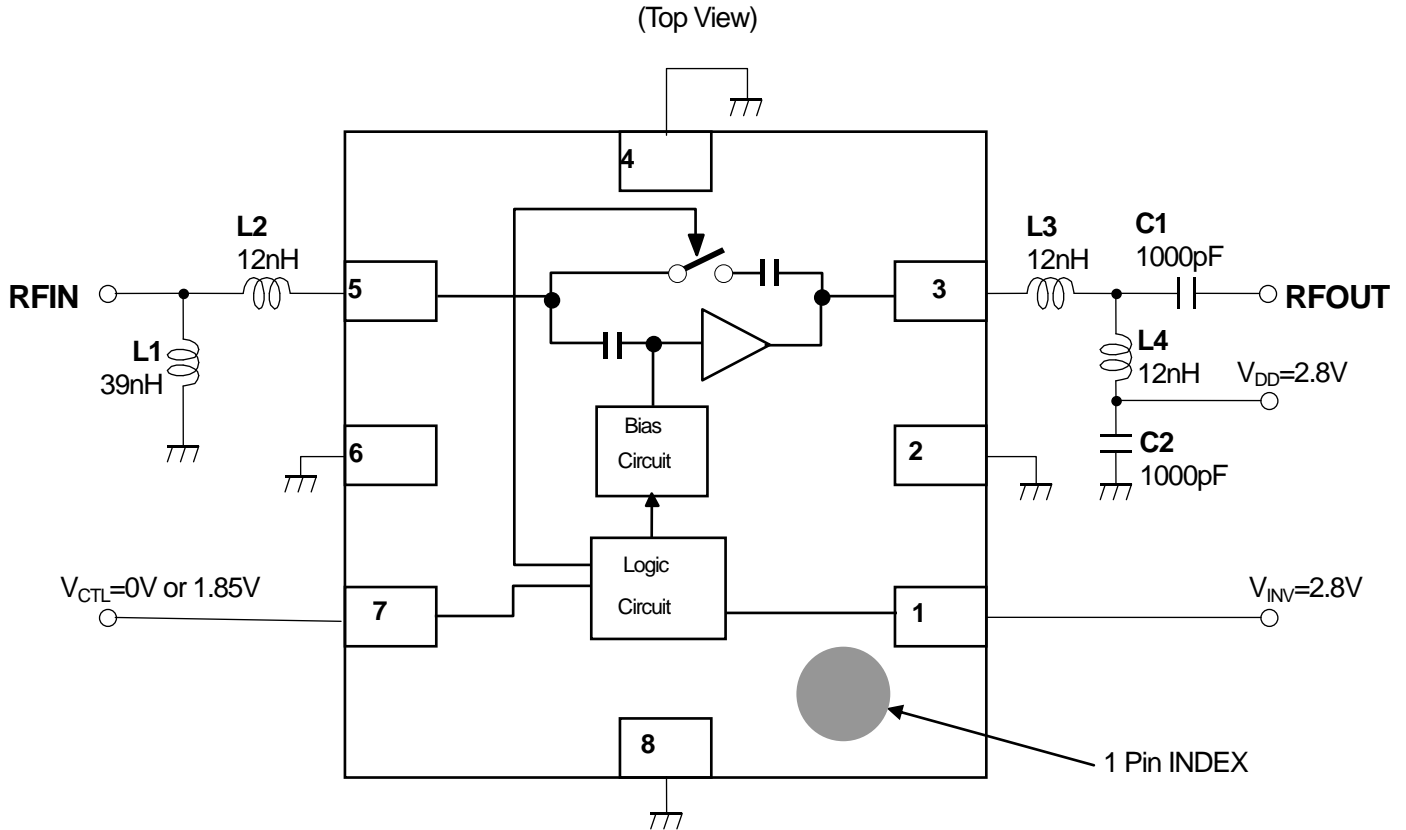


**IDD vs. Ambient Temperature**

(RF OFF)

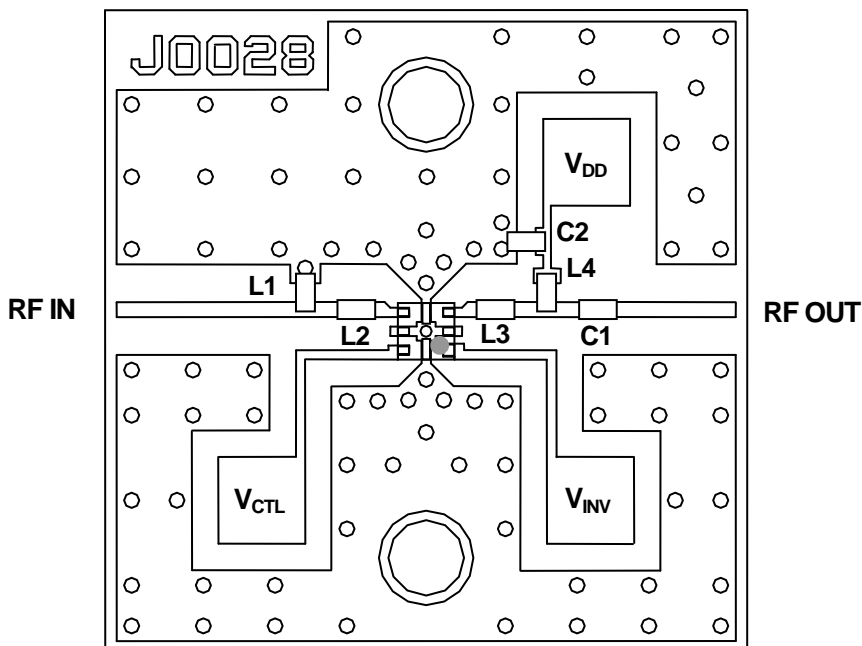


## APPLICATION CIRCUIT 1 ( $f_{RF}=880\text{MHz}$ )



## EVALUATION BOARD PCB LAYOUT 1 ( $f_{RF}=880\text{MHz}$ )

(Top View)



### Parts List 1 ( $f_{RF}=880\text{MHz}$ )

Parts ID	Notes
L1~L4	TAIYO-YUDEN (HK1005 series)
C1,C2	MURATA (GRM15 series)

PCB (FR-4) :

t=0.2mm

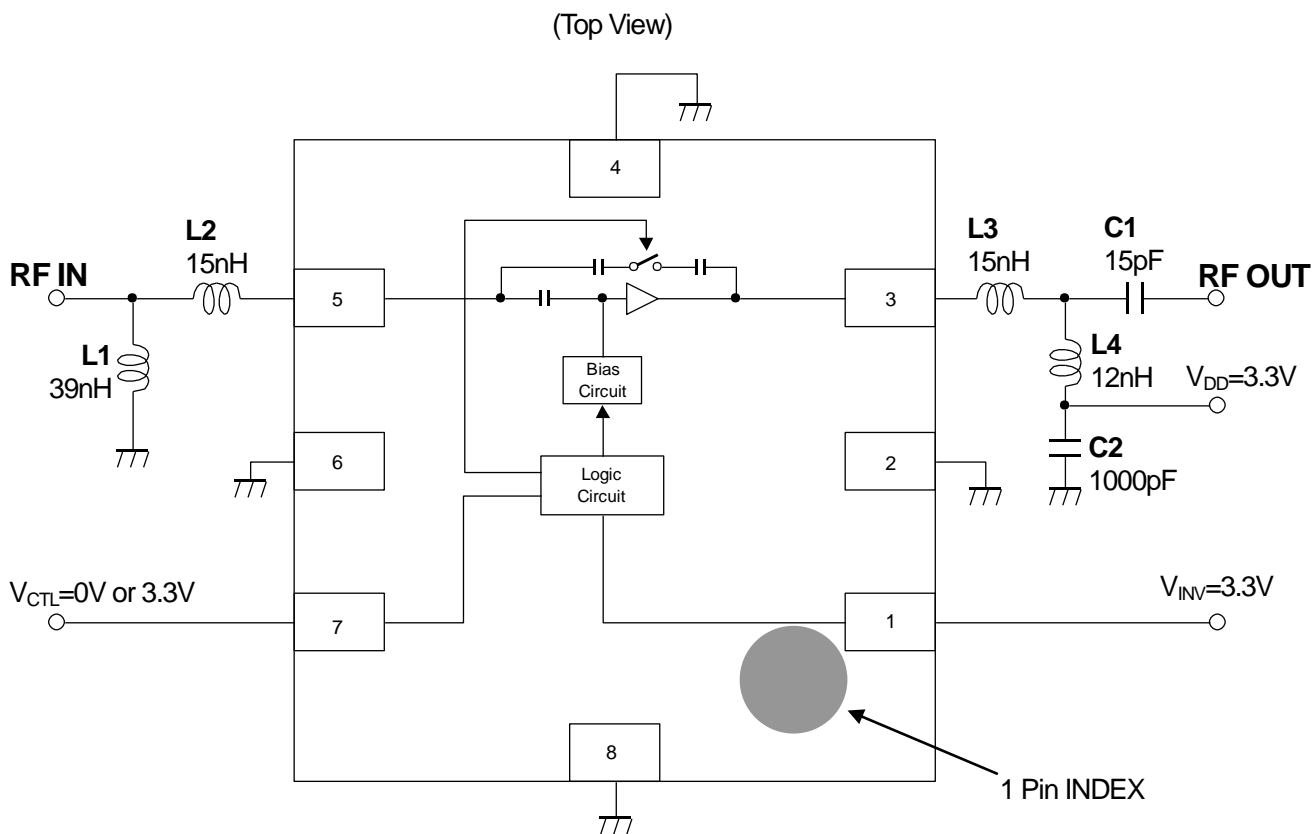
MICROSTRIP LINE WIDTH

=0.4mm ( $Z_0=50\Omega$ )

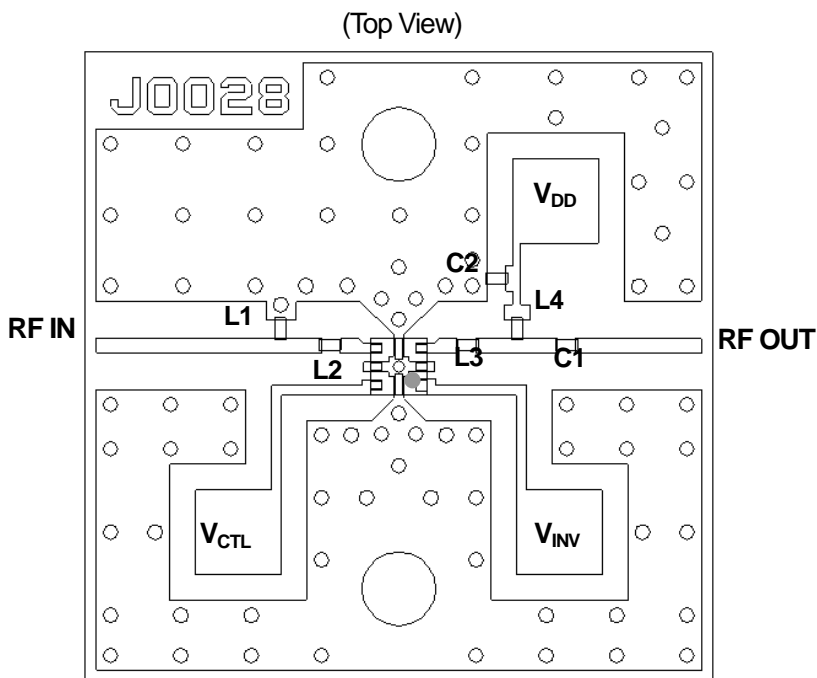
PCB SIZE =17.0mm X 17.0mm

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## APPLICATION CIRCUIT 2 ( $f_{RF}=760\text{MHz}$ )



## EVALUATION BOARD PCB LAYOUT 2 ( $f_{RF}=760\text{MHz}$ )



### Parts List 2 ( $f_{RF}=760\text{MHz}$ )

Parts ID	Notes
L1 ~ L4	MURATA (LQP03T_02 Series)
C1,C2	MURATA (GRM03 Series)

PCB (FR-4) :

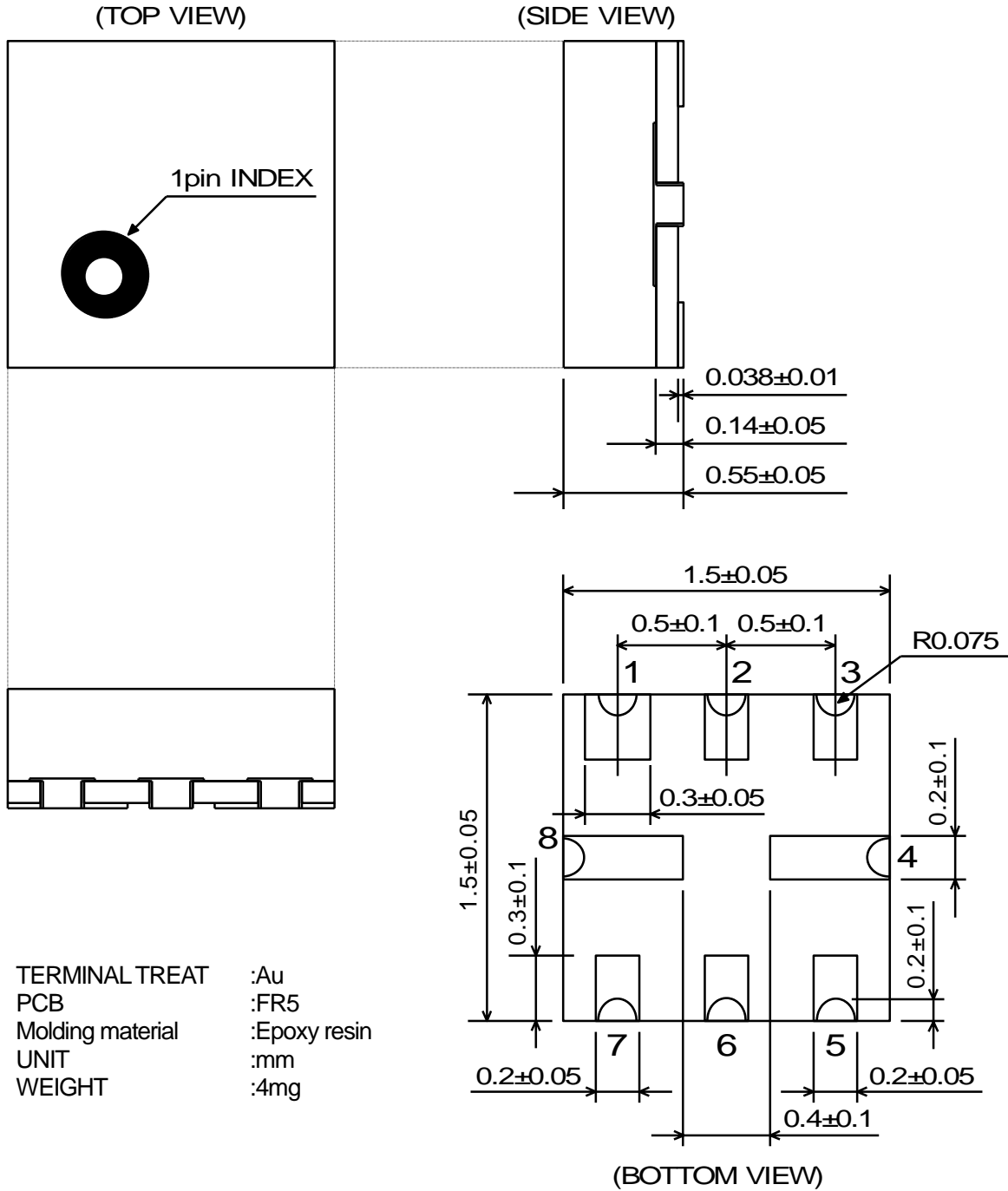
$t=0.2\text{mm}$

MICROSTRIP LINE WIDTH

$=0.4\text{mm}$  ( $Z_0=50\Omega$ )

PCB SIZE  $=17.0\text{mm} \times 17.0\text{mm}$

## PACKAGE OUTLINE (USB8-B6)



### Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

### [CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.